NSN 5962-01-207-8422

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 1.235 inches and 1.285 inches
Body Width:
Between 0.515 inches and 0.600 inches
Body Height:
Between 0.145 inches and 0.175 inches
Operating Tempurature Range:
-65.0 to 110.0 degrees celsius
Storage Tempurature Range:
-65.0 to 125.0 degrees celsius
End Application:
6675-01-179-2982 module, north fi
Features Provided:
Electrostatic sensitive and hermetically sealed and programmable and programmed and ultraviolet erasable
Inclosure Material:
Ceramic or glass or metal
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 6.0 volts power source
Time Rating Per Chacteristic:
450.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Fiig:

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